

#### 450V NPN HIGH VOLTAGE POWER TRANSISTOR

#### **Features**

- BV<sub>CEO</sub> > 450V
- BVcs > 700V
- BV<sub>EBO</sub> > 9V
- I<sub>C</sub> = 4A high Collector Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

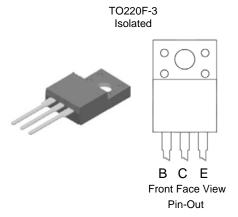
### **Applications**

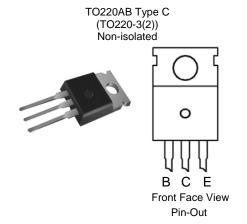
Low power AC-DC SMPS for:

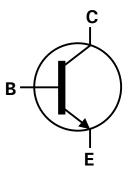
- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED lighting

### **Mechanical Data**

- Case: TO220F-3, TO220AB Type C
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Weight: TO220F-3: 1500mg (Approximate)
  TO220AB Type C : 2000mg (Approximate)







Device Schematic

### Ordering Information (Note 4)

Product	Package	Marking	Quantity
APT13005TF-G1	TO220F-3	APT13005TF-G1	1,000 per Box in Tubes
APT13005T-G1	TO220AB Type C (TO220-3(2))	APT13005T-G1	1,000 per Box in Tubes

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**





= Manufacturers' code marking
For TO220F-3, APT13005TF-G1 = Product Type Marking ID
For TO220AB Type C, APT13005T-G1 = Product Type Marking ID
YWW = Date Code Marking

e.g. 312 = Year 2013, Week 12.

8 = Assembly site code XX = Batch Number



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CES</sub>	700	V
Collector-Emitter Voltage	V <sub>CEO</sub>	450	V
Emitter-Base Voltage	$V_{EBO}$	9	V
Collector Current	Ic	4	Α
Peak Collector Current	I <sub>CM</sub>	8	Α
Base Current	Ι <sub>Β</sub>	2	Α
Peak Base Current	I <sub>BM</sub>	4	A

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

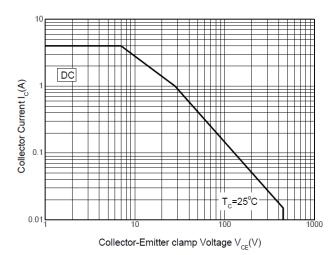
Characteristic	Symbol	Value	Unit		
Dower Dissipation @T + 25°C	For TO220F-3	0	28	- w	
Power Dissipation @T <sub>C</sub> = +25°C	For TO220AB Type C	P <sub>D</sub>	75		
Thermal Desistance, Junction to Cons	For TO220F-3	Б	4.5	°C/W	
Thermal Resistance, Junction to Case	For TO220AB Type C	R <sub>eJC</sub>	1.67		
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-65 to +150	°C		

## ESD Ratings (Note 6)

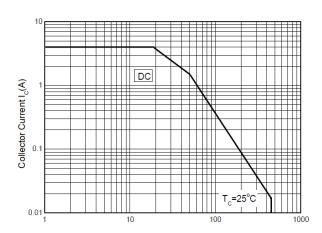
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Note: 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

### Safe Operating Areas (@T<sub>A</sub> = +25°C, unless otherwise specified.)



Safe Operating Areas (TO-220F-3 Package)



 $\label{eq:collector-Emitter clamp Voltage V} Collector-Emitter clamp Voltage V_{CE}(V) \\ Safe Operating Areas \\ (TO-220-3/TO-220-3(2) Package)$ 



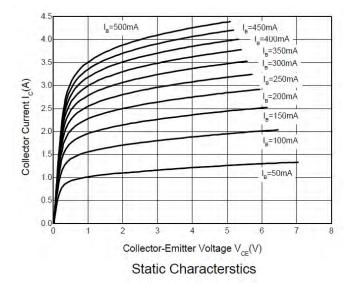
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

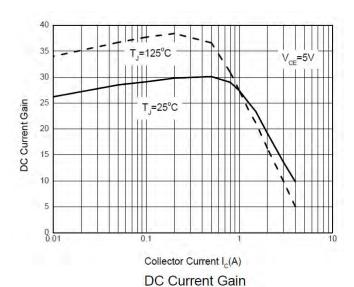
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	700	_	_	V	$I_C = 100 \mu A, V_{BE} = 0 V$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	450	_	_	V	I <sub>C</sub> = 100μA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	9	_	_	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CEV</sub>	_	_	10	μA	V <sub>CE</sub> = 700V, V <sub>BE</sub> = -1.5V
DC current transfer Static ratio (Note 5)	h <sub>FE</sub>	15 8		35 35	_ _	$I_{C} = 1A, V_{CE} = 5V$ $I_{C} = 2A, V_{CE} = 5V$
Collector-Emitter Saturation Voltage (Note 5)	V <sub>CE(sat)</sub>			0.3 0.6 0.9	V	$I_C = 1A$ , $I_B = 0.2A$ $I_C = 2A$ , $I_B = 0.5A$ $I_C = 4A$ , $I_B = 1A$
Base-Emitter Saturation Voltage (Note 5)	V <sub>BE(sat)</sub>		_ _	1.1 1.3	V	$I_C = 1A$ , $I_B = 0.2A$ $I_C = 2A$ , $I_B = 0.5A$
Output Capacitance	C <sub>ob</sub>	_	45	_	pF	V <sub>CB</sub> = 10V, f = 0.1MHz
Transition Frequency	f <sub>T</sub>	4	_	_	MHz	I <sub>C</sub> = 0.5A, V <sub>CE</sub> = 10V
Turn-on Time with Resistive Load	t <sub>on</sub>	_	_	0.8		
Storage Time with Resistive Load	ts	_	_	4.5	μs	$I_C = 2A$ , $V_{CC} = 125V$ $I_{B1} = -I_{B2} = 0.4A$
Fall Time with Resistive Load	t <sub>f</sub>	_	_	0.9		IB1 = -IB2 = U.4A

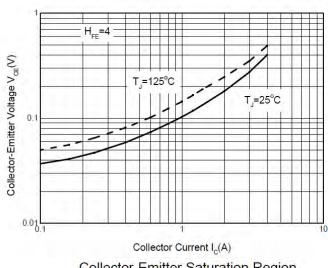
Note: 5. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

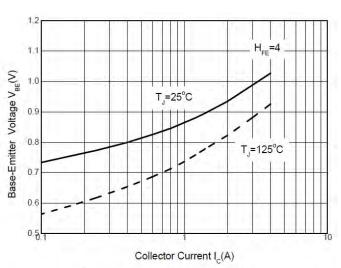


## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









Collector-Emitter Saturation Region

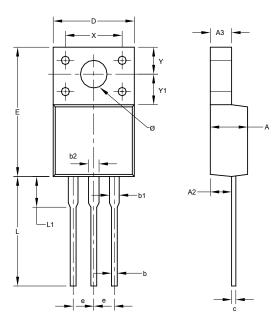
Base-Emitter Saturation Voltage



# **Package Outline Dimensions**

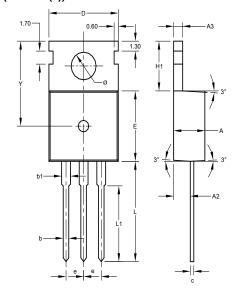
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

#### TO220F-3



TO220F-3					
Dim	Min Max		Тур		
Α	4.300	4.900	-		
A2	2.520	2.920	-		
A3	2.350	2.900	-		
b	0.550	0.900	-		
b1	1.000	1.400	-		
b2	1.100	1.500	-		
С	0.450	0.600	-		
D	9.70	10.30	-		
Е	14.70	16.00	-		
е	-	-	2.540		
L	12.50	13.50	-		
L1	2.790	4.500	-		
Х	6.90	7.10	-		
Υ	3.000	3.400	-		
Y1	3.370	3.900	-		
Ø	3.000	3.550	-		
All Dimensions in mm					

### TO220AB Type C (TO220-3(2))



TO220AB Type C						
Dim Min Max Typ						
Α	-	-	4.500			
A2	-	ı	2.400			
A3	-	1	1.300			
b	0.700	0.900	-			
b1	•	1	1.270			
С	0.400	0.600	-			
D	9.800	10.200	-			
Е	9.000	9.400	-			
е	-	1	2.54			
H1	6.300	6.700	-			
L	12.600	13.600	-			
L1	9.600	10.600	-			
Υ	-	-	11.100			
Ø	3.560	3.640	-			
All Dimensions in mm						

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.





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